

## N-Channel Enhancement Mode MOSFET

### 1. Product Information

#### 1.1 Features

- Surface-mounted package
- Low Thermal Resistance

#### 1.2 Applications

- LCD TV appliances
- High power inverter system
- LCDM appliances

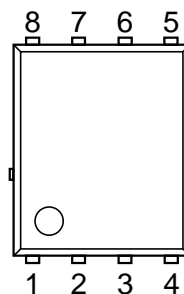
#### 1.3 Quick reference

- $BV \geq 40\text{ V}$
- $R_{DS(ON)} \leq 2.6\text{ m}\Omega @V_{GS} = 10\text{ V}$
- $P_{tot} \leq 147\text{ W}$
- $I_D \leq 100\text{ A}$

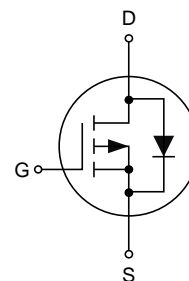
### 2. Pin Description

Pin	Description	Simplified Outline	Symbol
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1,2,3	Source
4	Gate
5,6,7,8	Drain



Top View  
PDFN5x6-8L



## 3. Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	Drain-Source Voltage	$T_C=25^{\circ}C$	40	-	V
$V_{GS}$	Gate-Source Voltage	$T_C=25^{\circ}C$	-	$\pm 20$	V
$I_D^{***}$	Drain Current (DC)	$T_C=25^{\circ}C, V_{GS}=10\text{ V}$	-	100	A
		$T_C=100^{\circ}C, V_{GS}=10\text{ V}$	-	60	A
$I_{DM}^{*,***}$	Drain Current (Pulsed)	$T_C=25^{\circ}C, V_{GS}=10\text{ V}$	-	240	A
$P_{tot}$	Drain power dissipation	$T_C=25^{\circ}C$	-	147	W
$T_{stg}$	Storage Temperature		-55	150	$^{\circ}C$
$T_J$	Junction Temperature		-	150	$^{\circ}C$
$I_S$	Continuous-Source Current	$T_C=25^{\circ}C$	-	100	A
$R_{\theta JA}^{**}$	Thermal Resistance-Junction to Ambient		-	62.5	$^{\circ}C/W$
$R_{\theta JC}^{**}$	Thermal Resistance-Junction to Case		-	0.85	

Notes :

- \* Pulse width  $\leq 300\ \mu s$ , duty cycle  $\leq 2\%$
- \*\* Mounted on Large Heat Sink
- \*\*\* Limited by bonding wire

## 4. Marking Information

Product Name	Marking
KJ8812G	<div style="background-color: black; color: white; padding: 5px; display: inline-block;"> <b>8812</b> <b>YWWXX</b> </div>

## 5. Ordering Code

Product Name	Package	Reel Size	Tape width	Quantity	Note
KJ8812G	PDFN 5x6-8L	13"	12 mm	5000	

Note: KUIJIEXIN defines "Green" as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC/JEDEC J-STD-020C)

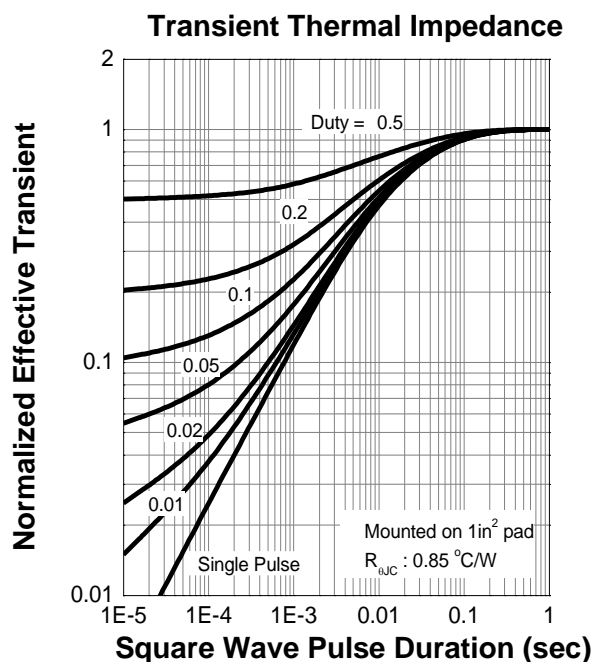
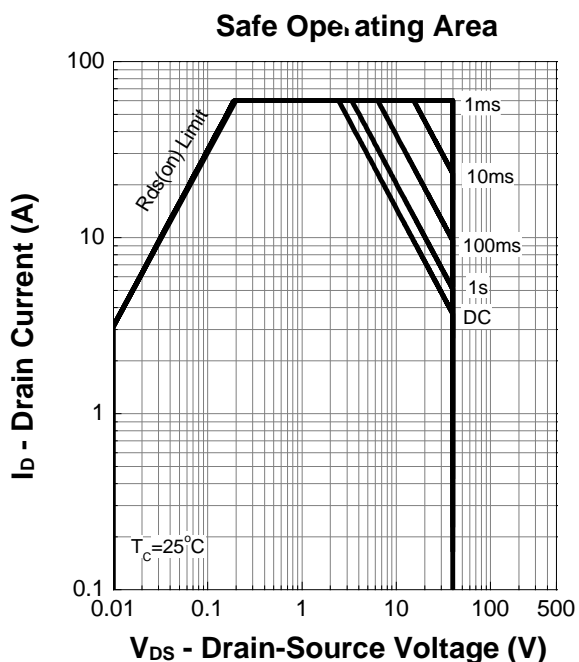
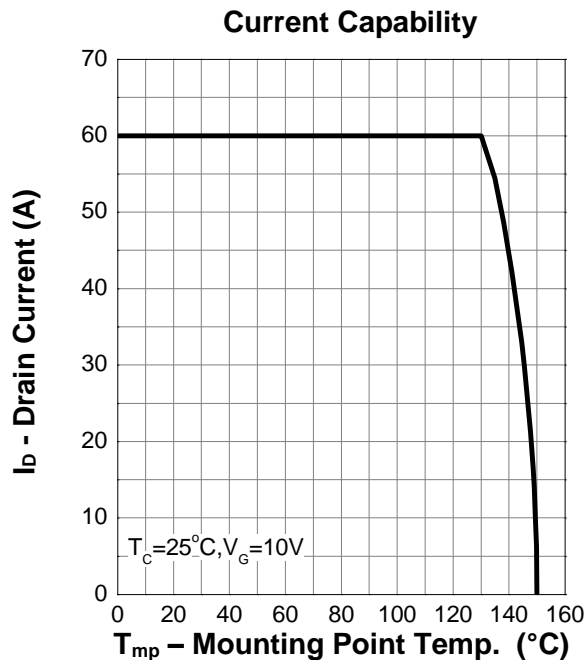
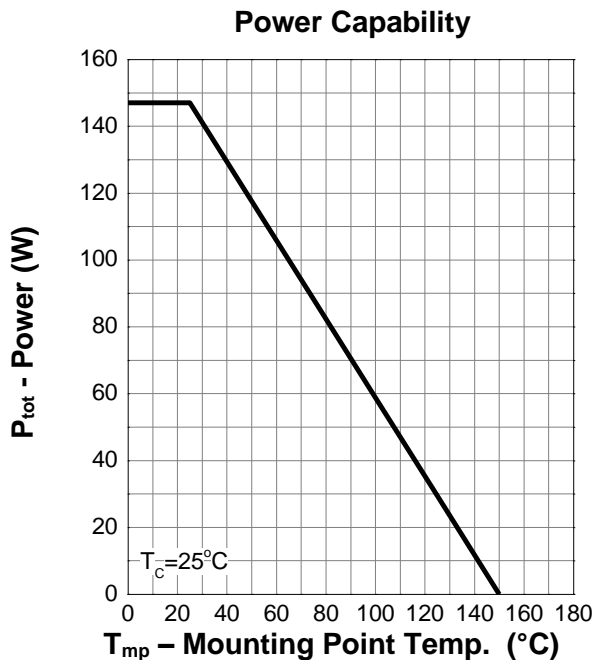
## 6. Electrical Characteristics (T<sub>A</sub>=25°C Unless Otherwise Noted )

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static Characteristics</b>						
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0 V, I <sub>DS</sub> =250 μA	40	-	-	V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>DS</sub> =250 μA	2.0	-	4.0	V
I <sub>DSS</sub>	Drain Leakage Current	V <sub>DS</sub> =32 V, V <sub>GS</sub> =0 V	-	-	1	μA
I <sub>GSS</sub>	Gate Leakage Current	V <sub>GS</sub> =0 V, V <sub>GS</sub> =±20 V	-	-	±100	nA
R <sub>DS(ON)</sub> <sup>a</sup>	On-State Resistance	V <sub>GS</sub> =10 V, I <sub>DS</sub> =20 A	-	2.1	2.6	mΩ
<b>Diode Characteristics</b>						
V <sub>SD</sub> <sup>a</sup>	Diode Forward Voltage	I <sub>SD</sub> =20 A, V <sub>GS</sub> =0 V	-	-	1.3	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>DS</sub> =20 A, V <sub>GS</sub> =0 V dI <sub>SD</sub> /dt=100 A/μs	-	38	-	ns
Q <sub>rr</sub>	Reverse Recovery Charge		-	30	-	nC
<b>Dynamic Characteristics<sup>b</sup></b>						
C <sub>iss</sub>	Input Capacitance	V <sub>GS</sub> =0 V, V <sub>DS</sub> =20 V Frequency=1 MHz	-	10509	-	pF
C <sub>oss</sub>	Output Capacitance		-	798	-	
C <sub>rss</sub>	Reverse Transfer Capacitance		-	207	-	
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DS</sub> =20 V, V <sub>GEN</sub> =10 V, R <sub>G</sub> =4.5 Ω, R <sub>L</sub> =1 Ω, I <sub>DS</sub> =20 A	-	42.5	-	ns
t <sub>r</sub>	Turn-on Rise Time		-	63	-	
t <sub>d(off)</sub>	Turn-off Delay Time		-	73.9	-	
t <sub>f</sub>	Turn-off Fall Time		-	49	-	
<b>Gate Charge Characteristics<sup>b</sup></b>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =20 V, V <sub>GS</sub> =10 V, I <sub>DS</sub> =20 A	-	143	-	nC
Q <sub>gs</sub>	Gate-Source Charge		-	59	-	
Q <sub>gd</sub>	Gate-Drain Charge		-	22.3	-	

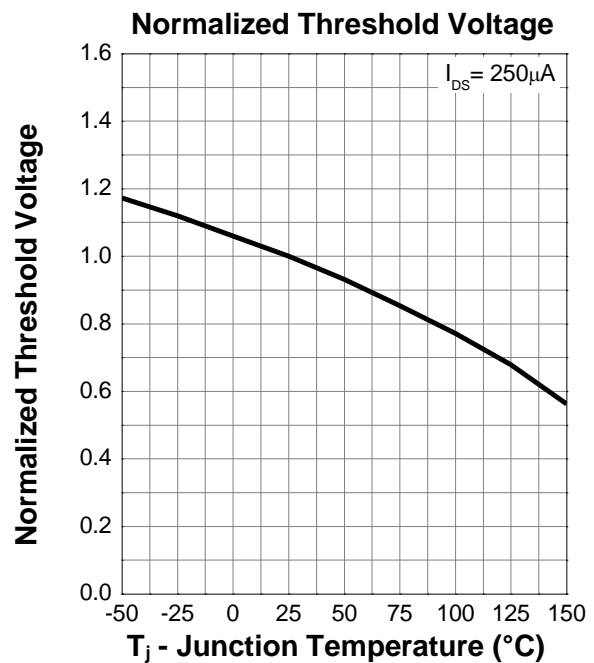
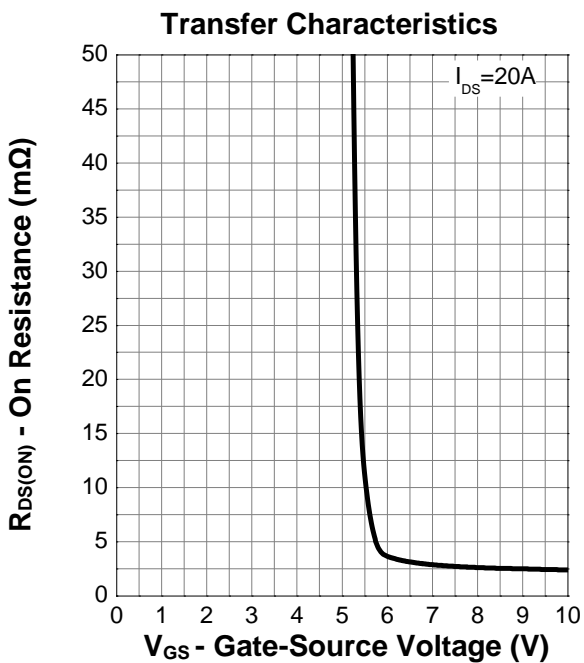
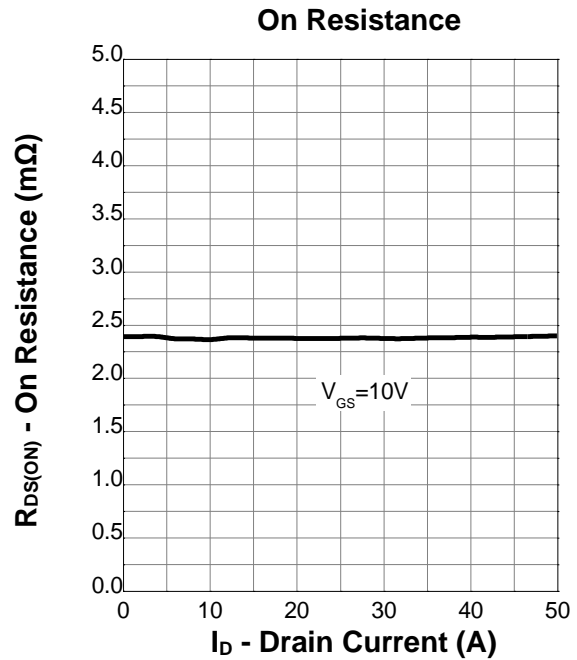
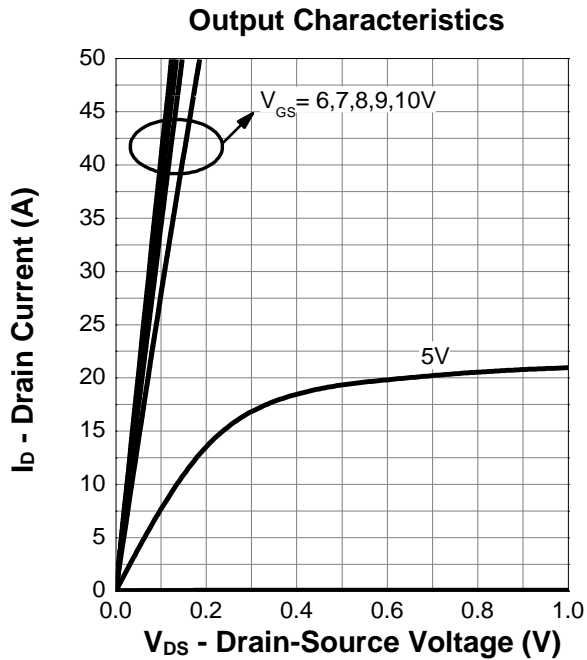
Notes:

- Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%
- Guaranteed by design, not subject to production testing

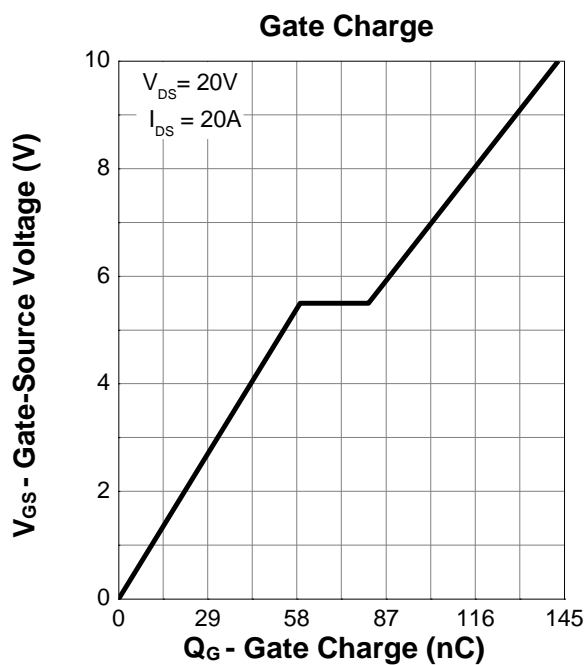
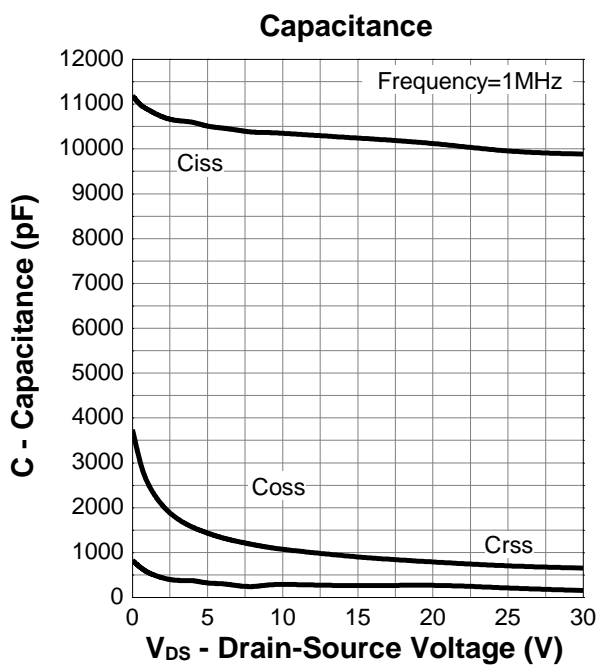
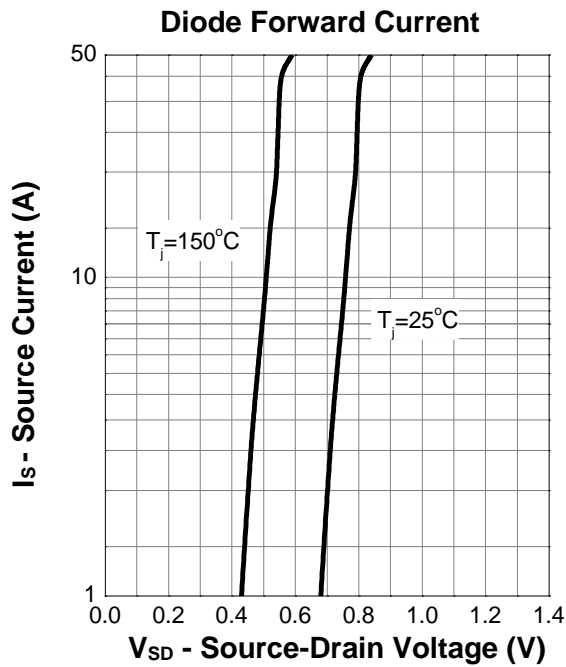
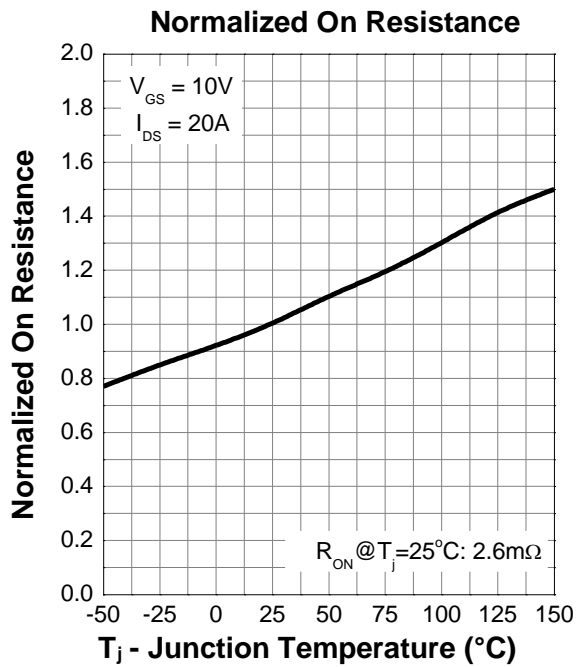
## 7. Typical Characteristics



## 7. Typical Characteristics (cont.)

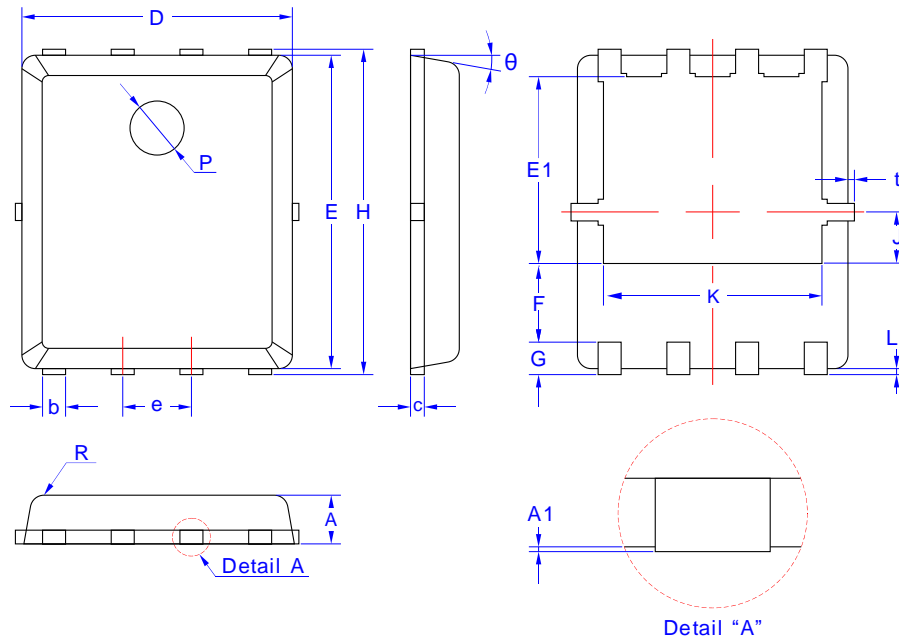


## 7. Typical Characteristics (cont.)



## 8. Package Dimensions

PDFN 5x6-8L Package



Symbol	Dimensions in Millimeters	
	MIN.	MAX.
A	0.80	1.00
A1	0.00	0.05
b	0.35	0.49
c	0.254 REF	
D	4.90	5.10
E	5.70	5.90
E1	3.40 REF	
e	1.27 BSC	
F	1.40 REF	
G	0.60 REF	
H	5.95	6.20
J	0.95 BSC	
K	4.00 REF	
L1	0.10	0.18
L	-	0.15
P	1.00 REF	
R	0.25 REF	
θ	6°	14°